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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of: Hiroshi YOSHIDA

Serial Number: Not Yet Assigned
(§371 of international application No. PCT/JP03/00139)

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For: METHOD FOR GETTERING TRANSITION METAL IMPURITIES IN
SILICON CRYSTAL

Attorney Docket No.:042440

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INFORMATION DISCLOSURE STATEMENT

Commissioner for Patents
P. O. Box 1450
Alexandria, VA 22313-1450

July 9, 2004

Sir:

In compliance with 37 CFR 1.56, Applicant calls to the attention of the Patent and Trademark Office the references listed on the attached PTO-1449.

A copy of each of the references is enclosed herewith, except for the U.S. reference.

In the event there are any fees due in connection with the filing of this paper, please charge

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Respectfully submitted,
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Enclosures: PTO-1449; References (10) and international search report.

INFORMATION DISCLOSURE STATEMENT PTO-1449	Atty. Docket No. 042440	Serial No. 10/501080 <i>New Appl.</i>
	Applicant(s): Hiroshi YOSHIDA	
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U.S. PATENT DOCUMENTS

Examiner Initial	Document No.	Name	Date	Class	Subclass	Filing Date (If appropriate)
AA	2001/0012686	Hamada	08/09/01			

FOREIGN PATENT DOCUMENTS

	Document No.	Date	Country	Translation (Yes or No)
AB	11-204534	07/30/99	Japan	Abstract. Cited in the int'l. search report.
AC	0 502 471	09/09/92	EPO	Yes. Cited in the int'l. search report.
AD	10-041311	02/13/98	Japan	Abstract. Cited in the int'l. search report.
AE	419 044	03/27/91	EPO	Yes. Cited in the int'l. search report.

OTHER DOCUMENTS

AF	C. Maddalon-Vinante et al.; Journal of the Electrochemical Society, Vol. 142, No. 2, pp.560-564, Feb. 1995. Cited in the int'l. search report.
AG	M. Nakamura, Applied Physics Letters, Vol. 79, No. 18, pp.2904-2906; October 29, 2001.
AH	M. Nakamura, Journal of the Electrochemical Society, Vol. 147, No. 2, pp. 796-798, 2000.
AI	Patent Abstracts of Japan, Pub. No. 10-303430 of 11/13/98. Cited in the specification.
AJ	Patent Abstracts of Japan, Pub. No. 2001-250957 of 09/14/01. Cited in the spec.
AK	Patent Abstracts of Japan, Pub. No. 2001-274405 of 10/05/01. Cited in the spec.

Examiner

Date Considered